

## Sound Processor with Built-in 3-band Equalizer BD37533FV

#### **General Description**

BD37533FV is a sound processor with built-in 3-band equalizer for car audio. A stereo input selector is available that functions to switch single end input and ground isolation input, input-gain control, main volume, loudness, 5ch fader volume, LPF for subwoofer and mixing input. Moreover, "Advanced switch circuit", which is an original ROHM technology, can reduce various switching noise (ex. No-signal, low frequency like 20Hz & large signal inputs). Also, "Advanced switch" makes microcomputer control easier, and constructs a high quality car audio system.

#### **Features**

- Reduced switching noise of input gain control, mute, main volume, fader volume, bass, middle, treble, loudness by using advanced switch circuit
- Built-in differential input selector that can make various combination of single-ended / differential input.
- Built-in ground isolation amplifier inputs, which is ideal for external stereo input.
- Built-in input gain controller reduces volume switching noise of a portable audio input.
- Decreased number of external components due to built-in 3-band equalizer filter, LPF for subwoofer and loudness filter. It is possible to freely control the Q, Gv, fo of the 3-band equalizer, fc of the LPFand Gv of loudness by I<sup>2</sup>C BUS control.
- A gain adjustment quantity of ±20dB with a 1 dB step gain adjustment is possible for the bass, middle and treble.
- Equipped with terminals for the subwoofer outputs. Also, the audio signal outputs of the front, rear and subwoofer can be chosen using the I<sup>2</sup>C BUS control
- Built-in mixing input, mixing attenuator.
- Energy-saving design resulting in low current consumption is achieved utilizing the BiCMOS process. It has the advantage in guality over scaling down the power heat control of the internal regulators
- Input pins and output pins are organized and separately laid out to keep the signal flow in one direction which consequently, simplify pattern layout of the set board and decrease the board dimensions
- It is possible to control I<sup>2</sup>C BUS with 3.3V / 5V

## **Applications**

It is optimal for car audio systems. It can also be used for audio equipment of mini Compo, micro Compo, TV etc

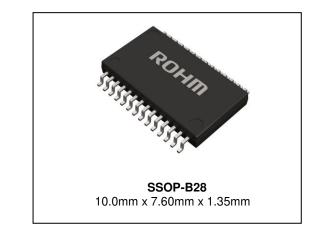
## Ke

ey Specifications	
Power Supply Voltage Range:	7.0V to 9.5V
Circuit Current (No Signal):	38mA (Typ)
Total Harmonic Distortion 1:	
(FRONT,REAR)	0.001% (Typ)
Total Harmonic Distortion 2:	
(SUBWOOFER)	0.002% (Typ)
Maximum Input Voltage:	2.3Vrms (Typ)
Cross-talk Between Selectors:	-100dB (Typ)
Volume Control Range:	+15dB to -79dB
Output Noise Voltage 1:	
(FRONT,REAR)	3.8µVrms (Typ)
Output Noise Voltage 2:	
(SUBWOOFER)	4.8µVrms (Typ)
Residual Output Noise Voltage:	1.8µVrms (Typ)

Operating Temperature Range: -40°C to +85°C

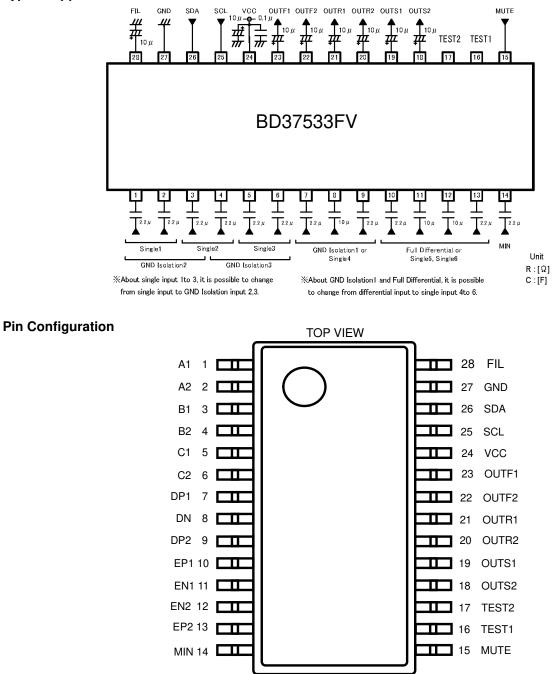
## Package

## W(Typ) x D(Typ) x H(Max)



OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

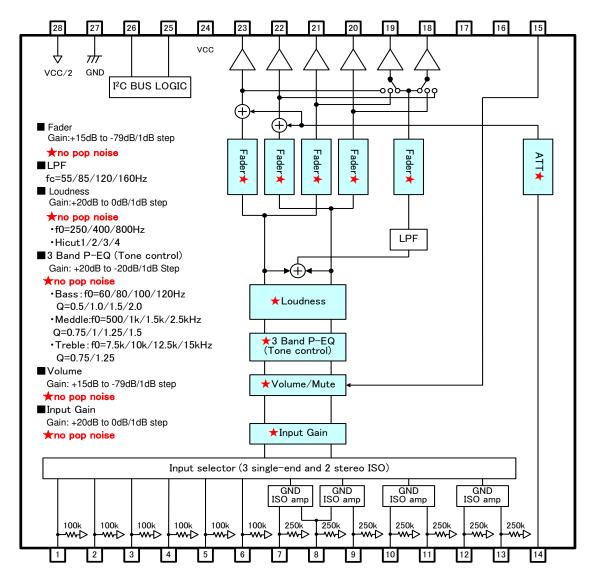
## **Typical Application Circuit**



## **Pin Descriptions**

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
1	A1	A input terminal of 1ch	15	MUTE	External compulsory mute terminal
2	A2	A input terminal of 2ch	16	TEST1	Test Pin
3	B1	B input terminal of 1ch	17	TEST2	Test Pin
4	B2	B input terminal of 2ch	18	OUTS2	Subwoofer output terminal of 2ch
5	C1	C input terminal of 1ch	19	OUTS1	Subwoofer output terminal of 1ch
6	C2	C input terminal of 2ch	20	OUTR2	Rear output terminal of 2ch
7	DP1	D positive input terminal of 1ch	21	OUTR1	Rear output terminal of 1ch
8	DN	D negative input terminal	22	OUTF2	Front output terminal of 2ch
9	DP2	D positive input terminal of 2ch	23	OUTF1	Front output terminal of 1ch
10	EP1	E positive input terminal of 1ch	24	VCC	Power supply terminal
11	EN1	E negative input terminal of 1ch	25	SCL	I <sup>2</sup> C Communication clock terminal
12	EN2	E negative input terminal of 2ch	26	SDA	I <sup>2</sup> C Communication data terminal
13	EP2	E positive input terminal of 2ch	27	GND	GND terminal
14	MIN	Mixing input terminal	28	FIL	VCC/2 terminal

## **Block Diagram**



## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power supply Voltage	Vcc	10.0	V
Input voltage	V <sub>IN</sub>	V <sub>cc</sub> +0.3 to GND-0.3	V
Power Dissipation	Pd	1.06 (Note 1)	W
Storage Temperature	Tstg	-55 to +150	°C

(Note 1) When mounted on the standar board (70 x 70 x 1.6(mm<sup>3</sup>), derate by 8.5mW/°C for Ta above 25°C.

Thermal resistance θja = 117.6(°C/W)

Material : A FR4 grass epoxy board (3% or less of copper foil area)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

## **Recommended Operating Conditions**

Parameter	Parameter Symbol Limit		Unit
Power Supply Voltage	Vcc	7.0 to 9.5	V
Temperature	Topr	-40 to +85	°C

## **Electrical Characteristics**

(Unless otherwise noted, Ta=25°C, V<sub>CC</sub>=8.5V, f=1kHz, V<sub>IN</sub>=1Vrms, Rg=600Ω, R<sub>L</sub>=10kΩ, A1 input, Input gain 0dB, Mute OFF, Volume 0dB, Tone control 0dB, Loudness 0dB, LPF OFF, Mixing OFF, Fader 0dB)

			,	Limit	<b>y -</b> ,		
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Circuit Current	la	-	38	48	mA	No signal
	Voltage Gain	Gv	-1.5	0	+1.5	dB	Gv=20log(Vout/VIN)
	Channel Balance	CB	-1.5	0	+1.5	dB	$CB = G_{V1} - G_{V2}$
	Total Harmonic Distortion 1 (FRONT,REAR)	THD+N1	-	0.001	0.05	%	V <sub>OUT</sub> =1Vrms BW=400Hz-30KHz
	Total Harmonic Distortion 2 (SUBWOOFER)	THD+N2	-	0.002	0.05	%	V <sub>OUT</sub> =1Vrms BW=400Hz-30KHz
<b>3AL</b>	Output Noise Voltage 1 (FRONT,REAR) *	V <sub>NO1</sub>	-	3.8	15	µVrms	Rg = 0Ω BW = IHF-A
GENERAL	Output Noise Voltage 2 (SUBWOOFER) *	V <sub>NO2</sub>	-	4.8	15	μVrms	Rg = 0Ω BW = IHF-A
GE	Residual Output Noise Voltage *	V <sub>NOR</sub>	-	1.8	10	μVrms	Fader = -∞dB Rg = 0Ω BW = IHF-A
	Cross-talk Between Channels *	СТС	-	-100	-90	dB	$Rg = 0\Omega$ CTC=20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW = IHF-A
	Ripple Rejection	RR	-	-70	-40	dB	f=1kHz V <sub>RR</sub> =100mVrms RR=20log(Vcc IN/Vout)
	Input Impedance(A, B, C)	RIN_S	70	100	130	kΩ	
	Input Impedance (D, E)	R <sub>IN_D</sub>	175	250	325	kΩ	
TOR	Maximum Input Voltage	VIM	2.1	2.3	-	Vrms	V <sub>IM</sub> at THD+N(V <sub>OUT</sub> )=1% BW=400Hz-30KHz
. SELECTOR	Cross-talk Between Selectors *	CTS	-	-100	-90	dB	$Rg = 0\Omega$ $CTS=20log(V_{OUT}/V_{IN})$ BW = IHF-A
INPUT S	Common Mode Rejection Ratio * (D, E)	CMRR	50	65	-	dB	XP1 and XN input XP2 and XN input CMRR=20log( $V_{IN}/V_{OUT}$ ) BW = IHF-A,[*X···D,E]

## **Electrical Characteristics – continued**

X				Limit			
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
GAIN	Minimum Input Gain	Gin_min	-2	0	+2	dB	Input gain 0dB V <sub>IN</sub> =100mVrms G <sub>IN</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
INPUT GAIN	Maximum Input Gain	Gin_max	+18	+20	+22	dB	Input gain +20dB V <sub>IN</sub> =100mVrms G <sub>IN</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	Gin_err	-2	0	+2	dB	GAIN=+20dB to +1dB
MUTE	Mute Attenuation *	Gmute	-	-105	-85	dB	Mute ON G <sub>MUTE</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW = IHF-A
	Maximum Gain	Gv_max	13	15	17	dB	$\label{eq:Volume} \begin{array}{l} \mbox{Volume} = 15 dB \\ \mbox{V}_{\rm IN} = 100 m \mbox{Vrms} \\ \mbox{G}_{\rm V} = 20 \mbox{log}(\mbox{V}_{\rm OUT}/\mbox{V}_{\rm IN}) \end{array}$
VOLUME	Maximum Attenuation *	Gv_min	-	-100	-85	dB	$      Volume = -\infty dB \\ G_V = 20 log(V_{OUT}/V_{IN}) \\ BW = IHF-A $
>	Attenuation Set Error 1	Gv_err1	-2	0	+2	dB	GAIN & ATT=+15dB to -15dB
	Attenuation Set Error 2	Gv_err2	-3	0	+3	dB	ATT=-16dB to -47dB
	Attenuation Set Error 3	Gv_err3	-4	0	+4	dB	ATT=-48dB to -79dB
	Maximum Boost Gain	G <sub>B_BST</sub>	18	20	22	dB	Gain=+20dB f=100Hz V <sub>IN</sub> =100mVrms GB=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
BASS	Maximum Cut Gain	<b>G</b> в_сит	-22	-20	-18	dB	Gain=-20dB f=100Hz V <sub>IN</sub> =2Vrms GB=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	$G_{B\_ERR}$	-2	0	+2	dB	Gain=+20dB to -20dB f=100Hz
щ	Maximum Boost Gain	Gm_bst	18	20	22	dB	Gain=+20dB f=1kHz V <sub>IN</sub> =100mVrms GM=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
MIDDLE	Maximum Cut Gain	<b>G</b> м_сит	-22	-20	-18	dB	Gain=-20dB f=1kHz V <sub>IN</sub> =2Vrms GM=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	Gm_err	-2	0	+2	dB	Gain=+20dB to -20dB f=1kHz
Щ	Maximum Boost Gain	GT_BST	18	20	22	dB	Gain=+20dB f=10kHz V <sub>IN</sub> =100mVrms GT=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
TREBL	Maximum Cut Gain	<b>G</b> т_сит	-22	-20	-18	dB	Gain=-20dB f=10kHz V <sub>IN</sub> =2Vrms GT=20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	Gt_err	-2	0	+2	dB	Gain=+20dB to -20dB f=10kHz
	Input Impedance	<b>R</b> IN_M	19	27	35	kΩ	
ŋ	Maximum Input Voltage	Vim_m	2.0	2.2	-	Vrms	V <sub>IM</sub> at THD+N(V <sub>OUT</sub> )=1 % BW=400Hz-30KHz
MIXING	Maximum Attenuation *	Gmx_min	-	-100	-85	dB	MIX=OFF Gмx=20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW=INF-A
	Maximum Gain	G <sub>MX_MAX</sub>	5	7	9	dB	ATT=+7dB G <sub>MX</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )

## **Electrical Characteristics - continued**

OCK				Limit			
BLO(	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
ER	Maximum Boost Gain	G <sub>F_BST</sub>	13	15	17	dB	$\label{eq:states} \begin{array}{l} Fader=15dB\\ V_{IN}=100mVrms\\ G_F=20log(V_{OUT}/V_{IN}) \end{array}$
SUBWOOFER	Maximum Attenuation *	GF_MIN	-	-100	-90	dB	fader = -∞dB G <sub>F</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW = IHF-A
Ing.	Gain Set Error	GF_ERR	-2	0	+2	dB	Gain=+15dB to +1dB
<b>\</b>	Attenuation Set Error 1	GF_ERR1	-2	0	+2	dB	ATT=-1dB to -15dB
EB	Attenuation Set Error 2	GF_ERR2	-3	0	+3	dB	ATT=-16dB to -47dB
FADI	Attenuation Set Error 3	GF_ERR3	-4	0	+4	dB	ATT=-48dB to -79dB
Ĕ	Output Impedance	Rout	-	-	50	Ω	V <sub>IN</sub> =100mVrms
	Maximum Output Voltage	Vом	2	2.2	-	Vrms	THD+N=1% BW=400Hz-30KHz
SS	Maximum Gain	Gl_max	17	20	23	dB	Gain 20dB V <sub>IN</sub> =100mVrms G <sub>L</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
LOUDNES	Gain Set Error	$G_{L\_ERR}$	-2	0	+2	dB	Gain=+20dB to +1dB

VP-9690A (Average value detection, effective value display) filter by Matsushita Communication is used for \* measurement. Phase between input / output is same.

Datasheet

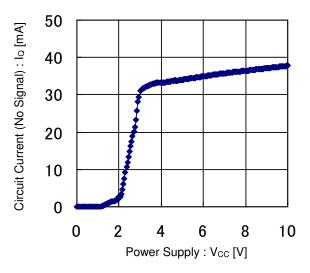
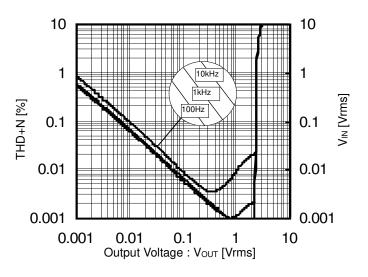
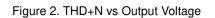


Figure 1. Circuit Current (No Signal) vs Power Supply Voltage





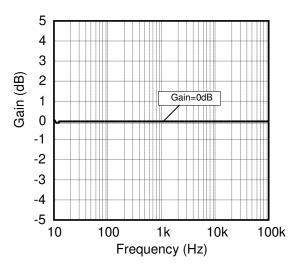


Figure 3. Gain vs Frequency

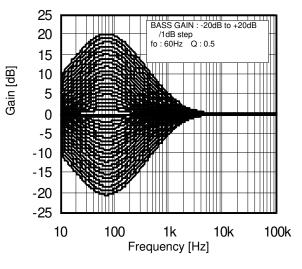
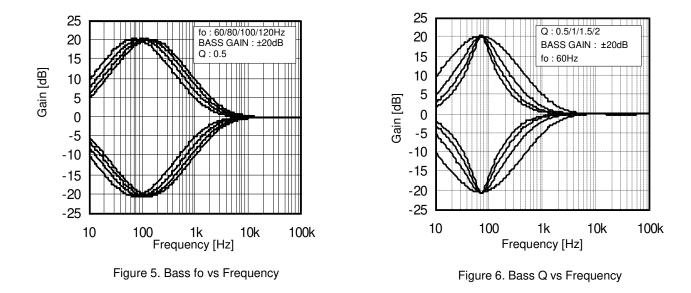
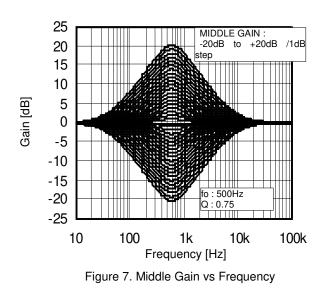


Figure 4. Bass Gain vs Frequency





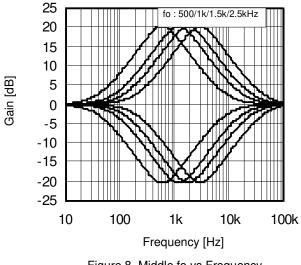
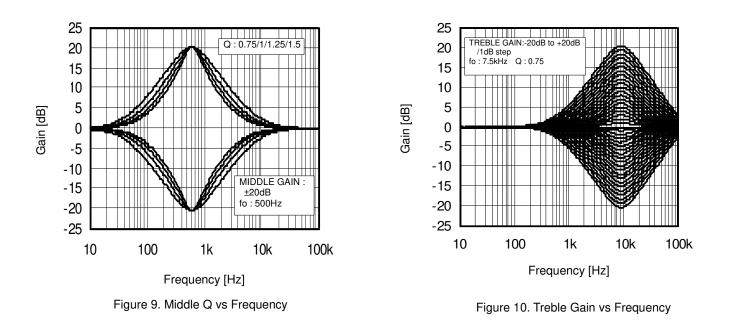


Figure 8. Middle fo vs Frequency



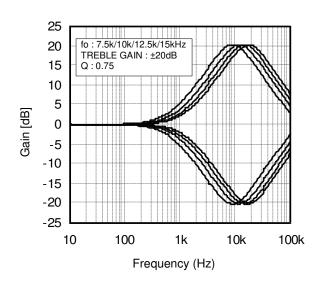


Figure 11. Treble fo vs Frequency

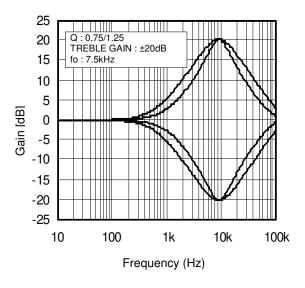


Figure 12. Treble Q vs Frequency

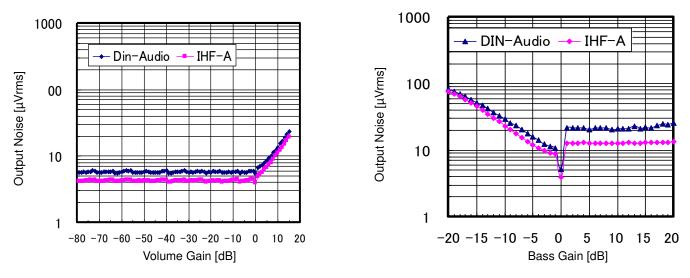


Figure 13. Output Noise vs Volume Gain



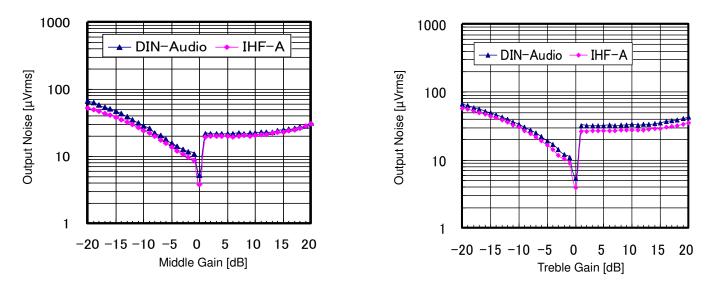


Figure 15. Output Noise vs Middle Gain



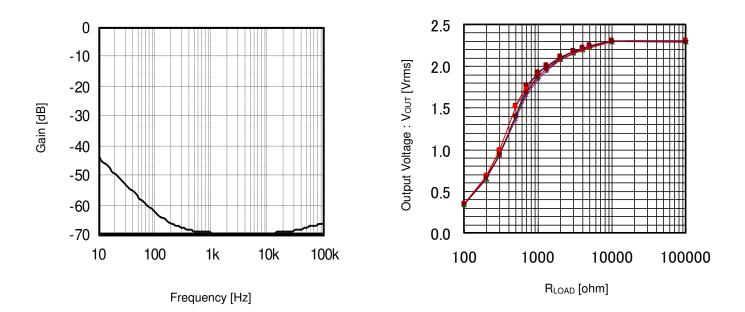


Figure 17. CMRR vs Frequency

Figure 18. Output Voltage vs R<sub>LOAD</sub>

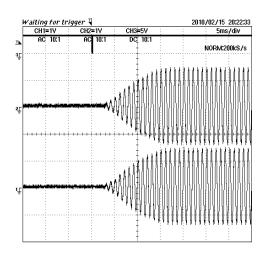


Figure 19. Advanced Switch 1

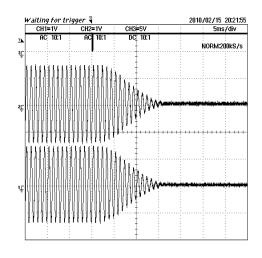
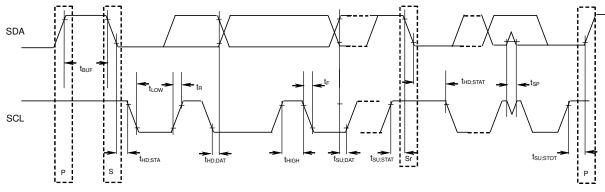


Figure 20. Advanced Switch 2

## **Timing Chart**

## **CONTROL SIGNAL SPECIFICATION**

(1) Electrical Specifications and Timing for Bus Lines and I/O Stages



#### Figure 21. Definition of Timing on the I<sup>2</sup>C-bus

Table 1 Characteristics of the SDA and SCL bus lines for  $I^2$ C-bus devices (Unless specified particularly, Ta=25°C, V<sub>CC</sub>=8.5V)

	Parameter	Symbol	Fast-mode	e l²C-bus	Unit
	Faidilielei	Symbol	Min	Max	Unit
1	SCL clock frequency	fscl	0	400	kHz
2	Bus free time between a S TO P and START condition	<b>t</b> BUF	1.3	-	μS
3	Hold time (repeated) START condition. After this period, the first clock	tun 071	0.6	-	
3	pulse is generated	thd;sta			μS
4	LOW period of the SCL clock	t <sub>LOW</sub>	1.3	-	μS
5	HIGH period of the SCL clock	tнigн	0.6	-	μS
6	Set-up time for a repeated START condition	tsu;sta	0.6	-	μS
7	Data hold time:	thd;dat	0.06 (Note)	-	μS
8	Data set-up time	tsu;dat	120	-	ns
9	Set-up time for STOP condition	tsu;sто	0.6	-	μS

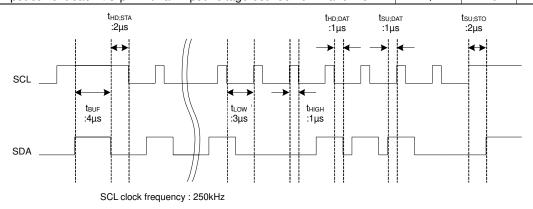
#### All values referred to VIH Min and VIL Max Levels (see Table 2).

(Note) The device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the VIH Min of the SCL signal) in order to bridge the undefined region of the falling edge of SCL.

About 7(t\_{HD;DAT}), 8(t\_{SU;DAT}), make the setup in which the margin is fully in .

#### Table 2 Characteristics of the SDA and SCL I/O stages for I<sup>2</sup>C-bus devices

	Parameter	Symbol	Fast-mod	Unit	
	Parameter	Symbol	Min	Max	Unit
10	LOW level input voltage:	VIL	-0.3	+1	V
11	HIGH level input voltage:	VIH	2.3	5	V
12	Pulse width of spikes which must be suppressed by the input filter.	tsp	0	50	ns
13	LOW level output voltage: at 3mA sink current	V <sub>OL1</sub>	0	0.4	V
14	Input current each I/O pin with an input voltage between 0.4V and 4.5V.	lı lı	-10	+10	μA



## Figure 22. A Command Timing Example in the I<sup>2</sup>C Data Transmission

(2) <u>I<sup>2</sup>C BUS FORMAT</u>

	MSB LSB		MSB I	SB	MSB	LSB		
S	Slave Address	Α	Select Address	Α	Dat	а	Α	Р
1bit	bit 8bit		8bit	1bit	8b	oit	1bit	1bit
	S = Start conditions (Recognition of start bit)							
	Slave Address = Recognition of slave address. 7 bits in upper order are voluntary.							
	The least significant bit is "L" due to writing.							
	А	= AC	KNOWLEDGE bit	Recognit	ion of acknow	ledgement)		
	Select Address	= Se	elect every of volum	e, bass a	nd treble.			
	Data = Data on every volume and tone.							
	P = Stop condition (Recognition of stop bit)							

## (3) <u>I<sup>2</sup>C BUS Interface Protocol</u>

## (a) Basic form

(u) L											
S	S Slave Address		Α	Select Addre	SS	Α	Data	Α	Р		
	MSB	LSB		MSB	LSB	N	ISB	LSB			

## (b) Automatic increment (Select Address increases (+1) according to the number of data.

ſ	S	Slave Address	А	Select Address	А	Data1	А	Data2	Α		DataN	А	Ρ
	l	MSB LSE	3 M	SB LSB	MS	SB LSB		MSB L	SB	MS	SB LSE	3	
					-	-	、 .	-	UВ	IVIC		,	

(Example) ①Data1 shall be set as data of address specified by Select Address.
 ②Data2 shall be set as data of address specified by Select Address +1.

③DataN shall be set as data of address specified by Select Address +N-1.

(c) Configuration unavailable for transmission (In this case, only Select Address1 is set.

S Slave	Address	Α	Select Addres	ss1	А	Data	Α	Select Ad	ddress 2	Α	Dat	ta A	Ρ
MSB	LSI	3	MSB L	SB	Μ	SB I	.SB	MSB	LSB	Ν	ISB	LSB	
			data is transmi				ddres	ss 2 next to	data, it is	reco	ogniz	ed	
		as	data, not as Sel	ect A	ddre	ess 2.							

## (4) Slave Address

I	MSB							LSB	
	A6	A5	A4	A3	A2	A1	A0	R/W	
	1	0	0	0	0	0	0	0	80H

(5) Select Address & Data

Items	Select Address	MSB			Da	ata			LSB	
items	(hex)	D7	D6	D5	D4	D3	D2	D1	D0	
Initial setup 1	01	Advanced switch ON/OFF	0	Advanced switch time of Input Gain/Volume Tone/Fader/Loudnes s/Mixing		0	1		switch time <i>I</i> ute	
Initial setup 2	02	LPF Phase	0		er Output lect	0	Su	bwoofer LP	F fc	
Initial setup 3	03	0	0	0	Loudn	iess fo	0	0	1	
Input Selector	05	Full-diff Type	0	0			Input selecto	nput selector		
Input gain	06	Mute ON/OFF	0	0			Input Gain			
Volume gain	20			١	/olume Gain	/ Attenuatio	n			
Fader 1ch Front	28				Fader Gain	/ Attenuatior	า			
Fader 2ch Front	29		Fader Gain / Attenuation							
Fader 1ch Rear	2A		Fader Gain / Attenuation							
Fader 2ch Rear	2B				Fader Gain	/ Attenuatior	า			
Fader Subwoofer	2C				Fader Gain	/ Attenuatior	า			
Mixing	30				Mixing Gain	/ Attenuation	n			
Bass setup	41	0	0	Bas	s fo	0	0	Bas	ss Q	
Middle setup	44	0	0	Mido	lle fo	0	0	Mide	dle Q	
Treble setup	47	0	0	Treb	le fo	0	0	0	Treble Q	
Bass gain	51	Bass Boost/ Cut	0	0			Bass Gain			
Middle gain	54	Middle Boost/ Cut	0	0	Middle Gain					
Treble gain	57	Treble Boost/ Cut	0	0	Treble Gain					
Loudness Gain	75	0	Loudne	ess Hicut Loudness Gain						
System Reset	FE	1	0	0	0	0	0	0	1	

Advanced switch

## Note

- 1. The Advanced Switch works in the latch part while changing from one function to another.
- 2. Upon continuous data transfer, the Select Address rolls over because of the automatic increment function, as shown below.

$$\rightarrow 01 \rightarrow 02 \rightarrow 03 \rightarrow 05 \rightarrow 06 \rightarrow 20 \rightarrow 28 \rightarrow 29 \rightarrow 2A \rightarrow 2B \rightarrow 2C$$

$$\rightarrow 30 \rightarrow 41 \rightarrow 44 \rightarrow 47 \rightarrow 51 \rightarrow 54 \rightarrow 57 \rightarrow 75$$

- 3. Advanced switch is not used for the functions of input selector and subwoofer output select etc. Therefore, please turn on MUTE when changing the settings of this side of a set.
- 4. When using Mute function of this IC at the time of changing input selector, please switch mute ON/OFF for waiting advanced-mute time.

Select address 01 (hex	)							
Time	MSB	Α	dvanc	ed swi	tch tim	ne of N	lute	LSB
Time	D7	D6	D5	D4	D3	D2	D1	D0
0.6msec	Advanced		Advanced	switch time		-	0	0
1.0msec	Advanced Switch	0	of Input ga	ain/Volume	0		0	1
1.4msec	ON/OFF	0	Tone/Fade	r/Loudness	0	I	1	0
3.2msec			/Mixing				1	1

Time	MSB	Advanced switch time of Input gain/Volume/Tone/Fader/Loudness/Mixing							
	D7	D6	D5	D4	D3	D2	D1	D0	
4.7 msec	A du conce e d		0	0	-	1			
7.1 msec	Advanced	0	0	1			Advanced switch Time of Mute		
11.2 msec	Switch ON/OFF		1	0	0	1			
14.4 msec			1	1					

Mode	MSB	Advanced switch ON/OFF						LSB	
Mode	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	0	0	Advanced switch time of Input gain/Volume Tone/Fader/Loudness /Mixing		0	1	Advanced switch		
ON	1	0			0	•	Time o	of Mute	

Select address 02(hex	)							
fc	MSB		LSB					
IC.	D7	D6	D5	D4	D3	D2	D1	D0
OFF						0	0	0
55Hz						0	0	1
85Hz		0	Subwoof	er Output	0	0	1	0
120Hz	LPF Phase	0		lect	0	0	1	1
160Hz						1	0	0
Prohibition							Other setting	3

Mode	MSB		Subw	oofer C	Dutput	LSB		
INIQUE	D7	D6	D5	D4	D3	D2	D1	D0
LPF		0	0	0				
Front			0	1		0		- ,
Rear	LPF Phase		1	0	0	Su	bwoofer LPF	- IC
Prohibition			1	1				

Phase	MSB				LSB			
FlidSe	D7	D6	D5	D4	D3	D2	D1	D0
0°	0	0	Subwoof	er output	0	Su	bwoofer LPF	= fo
180°	1	0	se	lect	0	50		

## Select address 03(hex)

f0	MSB			Loud	ness fo			LSB
10	D7	D6	D5	D4	D3	D2	D1	D0
250Hz				0	0			
400Hz	0	0	0	0	1	0	0	1
800Hz	0	0	0	1	0	0	U	
Prohibition				1	1			

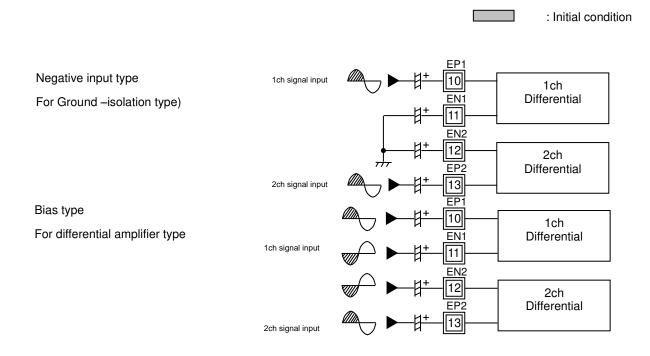
: Initial Condition

#### Select address 05(hex)

Mada		1	MSB		Ir	iput S	Select	or		LSB
Mode	OUTF1	OUTF2	D7	D6	D5	D4	D3	D2	D1	D0
A	A1	A2				0	0	0	0	0
В	B1	B2				0	0	0	0	1
С	C1	C2				0	0	0	1	0
D single	DP1	DP2				0	0	0	1	1
E1 single	EP1	EN1				0	1	0	1	0
E2 single	EN2	EP2	Full-diff	0	0	0	1	0	1	1
A diff	A1	B1	bias type select	0	0	0	1	1	1	1
C diff	B2	C2	Select			1	0	0	0	0
D diff	DP1	DP2				0	0	1	1	0
E full diff	EP1	EP2				0	1	0	0	0
Inp	ut SHORT		]			0	1	0	0	1
P	Prohibition					Other setting				

Input SHORT : The input impedance of each input terminal is lowered from  $100k\Omega(Typ)$  to  $6 k\Omega(Typ)$ . (For quick charge of coupling capacitor)

Mode	MSB		Fu	MSB Full-diff Bias Type Select								
Mode	D7	D6	D5	D4	D3	D2	D1	D0				
Negative Input	0	0	0		tor							
Bias	ias 1 0 0 Input Selector											



Gain	MSB			Input	Gain			LS
Gain	D7	D6	D5	D4	D3	D2	D1	DC
0dB				0	0	0	0	0
1dB				0	0	0	0	1
2dB				0	0	0	1	0
3dB				0	0	0	1	1
4dB				0	0	1	0	0
5dB				0	0	1	0	1
6dB				0	0	1	1	0
7dB				0	0	1	1	1
8dB				0	1	0	0	0
9dB				0	1	0	0	1
10dB				0 1 0	1	0		
11dB	Mute	0	0	0	1	0	1	1
12dB	ON/OFF	0	0	0	1	1	0	0
13dB				0	1	1	0	1
14dB			0	0	1	1	1	0
15dB				0	1	1	1	1
16dB				1	0	0	0	0
17dB				1	0	0	0	1
18dB				1	0	0	1	0
19dB				1	0	0	1	1
20dB				1	0	1	0	0
				1	1	0	1	1
Prohibition				:	:	:	:	:
			1	1	1	1	1	

Mode	MSB		Ν	Aute C	N/OFI	F		LSB
Mode	D7	D6	D5	D4	D3	D2	D1	D0
OFF	0	0	0			Input Gain		
ON	1	0	0			input Gain		

: Initial condition

Gain & ATT	MSB	Vo	ol, Fad	er Gai	n / Atte	enuatio	on	LSB
Gaill & ATT	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
	0	0	0	0	0	0	0	1
Prohibition	:	:	:	:	:	:	:	:
	0	1	1	1	0	0	0	0
15dB	0	1	1	1	0	0	0	1
14dB	0	1	1	1	0	0	1	0
13dB	0	1	1	1	0	0	1	1
:	:	:	:	:	:	:	:	:
-77dB	1	1	0	0	1	1	0	1
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition	:	:	:	:	:	:	:	:
	1	1	1	1	1	1	1	0
-∞dB	1	1	1	1	1	1	1	1

## Select address 20, 28, 29, 2A, 2B, 2C (hex)

Select address 30(hex)

Gain & ATT	MSB		Mixing	Gain	/ Atten	uation		LSB
Gaill & ATT	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
	0	0	0	0	0	0	0	1
Prohibition	:	:	:	:	:	:	:	:
	0	1	1	1	1	0	0	0
7dB	0	1	1	1	1	0	0	1
6dB	0	1	1	1	1	0	1	0
5dB	0	1	1	1	1	0	1	1
:	:		:	:	:	:	:	:
-77dB	1	1	0	0	1	1	0	1
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition	:	:	:	:	:	:	:	:
	1	1	1	1	1	1	1	0
MIX OFF	1	1	1	1	1	1	1	1

: Initial condition

#### Select address 41(hex)

Q factor	MSB	B Bass Q factor					LSB	
QTACION	D7	D6	D5	D4	D3	D2	D1	D0
0.5							0	0
1.0	0	0	Bas	a fa	0	0	0	1
1.5	0	0	Das	5 10			1	0
2.0							1	1

fo	fo MSB				fo			LSB
10	D7	D6	D5	D4	D3	D2	D1	D0
60Hz			0	0				
80Hz		0	0	1		0	Ba	ass actor
100Hz	0	0	1	0	0	0	Q fa	actor
120Hz	7		1	1				

#### Select address 44(hex)

Q factor	MSB		Mic	ddle	Q facto	or		LSB
Qiacioi	D7	D6	D5	D4	D3	D2	D1	D0
0.75							0	0
1.0	0	0	Mide	dle fo	0	0	0	1
1.25	0	0	IVIICO		0	0	1	0
1.5							1	1

fo	fo MSB			Middle fo LSB					
10	D7	D6	D5	D4	D3	D2	D1	D0	
500Hz			0	0					
1kHz	0	0	0	1	0	0	Mic	ddle actor	
1.5kHz	0	0	1	0	0	0	Q fa	actor	
2.5kHz			1	1					

## Select address 47 (hex)

Q factor	MSB		Tre	eble	Q facto		LSB	
	D7	D6	D5	D4	D3	D2	D1	D0
0.75	0	0	Troh	la fa	0	0	0	0
1.25	0	0	Treble fo		0	0	0	1

fo	MSB			Treble	e fo			LSB
fo	D7	D6	D5	D4	D3	D2	D1	D0
7.5kHz			0	0				
10kHz	0	0	0	1	0	0	0	Treble
12.5kHz	0	0	1	0	0	0	0	Q factor
15kHz			1	1				

: Initial condition

Coin	MSB		Bass/N	/iddle/	Treble	Gain		LS
Gain	D7	D6	D5	D4	D3	D2	D1	
0dB				0	0	0	0	
1dB				0	0	0	0	
2dB				0	0	0	1	
3dB				0	0	0	1	
4dB				0	0	1	0	
5dB				0	0	1	0	
6dB				0	0	1	1	
7dB				0	0	1	1	
8dB				0	1	0	0	
9dB				0	1	0	0	
10dB	Bass/			0	1	0	1	
11dB	Middle/			0	1	0	1	
12dB	Treble	0	0	0	1	1	0	
13dB	Boost	•		0	1	1	0	
14dB	/cut			0	1	1	1	
15dB				0	1	1	1	
16dB				1	0	0	0	
17dB				1	0	0	0	
18dB				1	0	0	1	
19dB				1	0	0	1	
20dB				1	0	1	0	
				1	0	1	0	
Prohibition				:	:	:	:	
Prohibition				1	1	1	1	
				1	1	1	1	

Mode	MSB	Bas	ss/Mid	dle/Tre	eble Bo	oost/C	ut	LSB
wode	D7	D6 D5 D4 D3 D2 D1 [						
Boost	0	0	0		Bacc	Middle/Troble	Gain	
Cut	1	0	0 0 Bass/Middle/Treble Gain					

Γ

: Initial condition

Mode	MSB		Loudness Hicut							
wode	D7	D6	D5	D4	D3	D2	D1	D0		
Hicut1		0	0							
Hicut2	0	0	1	]		oudness Ga	'n			
Hicut3	0	1	0		L	ouuness Ga				
Hicut4		1	1							
	MSB		L	oudne	ess Ga	in		LS		
Gain	D7	D6	D5	D4	D3	D2	D1	 D0		
0dB				0	0	0	0	0		
1dB				0	0	0	0	1		
2dB				0	0	0	1	0		
3dB				0	0	0	1	1		
4dB				0	0	1	0	0		
5dB				0	0	1	0	1		
6dB				0	0	1	1	0		
7dB				0	0	1	1	1		
8dB				0	1	0	0	0		
9dB				0	1	0	0	1		
10dB				0	1	0	1	0		
11dB				0	1	0	1	1		
12dB	0	Loudne	Loudness Hicut		1	1	0	0		
13dB				0	1	1	0	1		
14dB				0	1	1	1	0		
15dB				0	1	1	1	1		
16dB				1	0	0	0	0		
17dB				1	0	0	0	1		
18dB				1	0	0	1	0		
19dB				1	0	0	1	1		
20dB				1	0	1	0	0		
				1	0	1	0	1		
Prohibition				:	:	:	:	:		
				1	1	1	1	1		

: Initial condition

## (6) About Power ON Reset

Built-in IC initialization is made during power ON of the supply voltage. Please send initial data to all addresses at supply voltage on. Also, please turn ON MUTE at the set side until initial data is sent.

Parameter	Symbol		Limit		Unit	Conditions	
Falamelei	Symbol	Min	Тур	Max	Unit	Conditions	
Rise Time of VCC	trise	33	-	-	µsec	$V_{\text{CC}}$ rise time from 0V to 5V	
VCC Voltage of Release Power ON Reset	VPOR	-	4.1	-	V		

## (7) About External Compulsory Mute Terminal

It is possible to forcibly set Mute from the outside by setting the input voltage at the MUTE terminal.

Mute Voltage Condition	Mode
GND to 1.0V	MUTE ON
2.3V to V <sub>CC</sub>	MUTE OFF

Establish the voltage of MUTE in the condition to be defined.

## **Application Information**

## 1. Function and Specifications

Function			Specifications						
	(Stereo input)								
	Single-End/Diff/Full-Diff								
	-		of single-end/dif	f/full-diff as follows )					
	(Possible to set the number of single-end/diff/full-diff as follow Single-End Differential Full-Differentia								
Input	Mode 1		3	1					
selector	Mode 2	1	2	1					
	Mode 3	3	1	1					
	Mode 4 Mode 5	<u>4</u> 5	0	<u> </u>					
	Mode 5 Mode 6	6	0	0					
			ombination of inp						
Input	• +20dB to	0dB (1dB step)	)						
gain · Possible to use "Advanced switch" for prevention of switching noi									
Mute									
Volume	・+15dB to	-79dB (1dB ste	ep), -∞dB						
volume	Possible to use "Advanced switch" for prevention of switching is								
	• +20dB to -20dB (1dB step)								
Bass	· Q=0.5, 1, 1.5, 2								
Dass	• fo=60, 80, 100, 120Hz								
	Possible to use "Advanced switch" when changing gain								
	<ul> <li>+20dB to -20dB (1dB step)</li> </ul>								
Middle	· Q=0.75, 1, 1.25, 1.5								
	• fo=500, 1k, 1.5k 2.5kHz								
	Possible to use "Advanced switch" when changing gain								
	<ul> <li>+20dB to</li> <li>Q=0.75, 1</li> </ul>	-20dB (1dB ste	eb)						
Treble									
110010	• fo=7.5k, 10k, 12.5k, 15kHz								
	Possible to use "Advanced switch" when changing gain								
Fader	・+15dB to	-79dB(1dB ste	p), -∞dB						
rauer	Possible to use "Advanced switch" for prevention of switching noise								
	· 20dB to 0	dB(1dB step)							
Loudness	· fo=250/40	0/800Hz							
	Possible to use "Advanced switch" for prevention of switching noise								
LPF	• fc=55/85/	120/160Hz, pas	SS						
	<ul> <li>Phase sh</li> </ul>	ft (0°/180°)							
	・ Monaural	input							
Mixing		79dB (1dB step							
	Possible 1	o use "Advanc	ed switch" for pre	evention of switching	noise.				

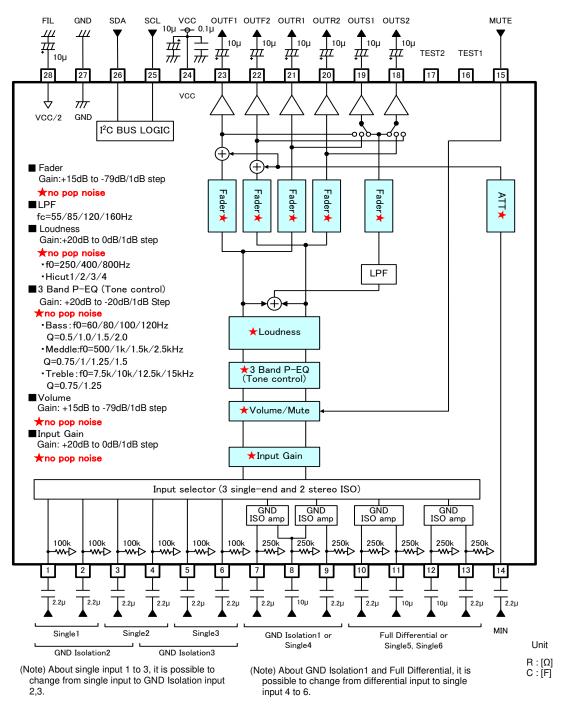
## 2. Volume / Fader Volume / Mixing Attenuation of the Details

2. Volume	; / Fau		Juille			llenu	alion		e Dela	115								
(dB)	D7	D6	D5	D4	D3	D2	D1	D0		(dB)	D7	D6	D5	D4	D3	D2	D1	D0
+15	0	1	1	1	0	0	0	1		-33	1	0	1	0	0	0	0	1
+14	0	1	1	1	0	0	1	0		-34	1	0	1	0	0	0	1	0
+13	0	1	1	1	0	0	1	1		-35	1	0	1	0	0	0	1	1
+12	0	1	1	1	0	1	0	0		-36	1	0	1	0	0	1	0	0
+11	0	1	1	1	0	1	0	1		-37	1	0	1	0	0	1	0	1
+10	0	1	1	1	0	1	1	0		-38	1	0	1	0	0	1	1	0
+9	0	1	1	1	0	1	1	1		-39	1	0	1	0	0	1	1	1
+8	0	1	1	1	1	0	0	0		-40	1	0	1	0	1	0	0	0
+7	0	1	1	1	1	0	0	1		-41	1	0	1	0	1	0	0	1
+6	0	1	1	1	1	0	1	0		-42	1	0	1	0	1	0	1	0
+5	0	1	1	1	1	0	1	1		-43	1	0	1	0	1	0	1	1
+4	0	1	1	1	1	1	0	0		-44	1	0	1	0	1	1	0	0
+3	0	1	1	1	1	1	0	1		-45	1	0	1	0	1	1	0	1
+2	0	1	1	1	1	1	1	0		-46	1	0	1	0	1	1	1	0
+1	0	1	1	1	1	1	1	1		-47	1	0	1	0	1	1	1	1
0	1	0	0	0	0	0	0	0		-48	1	0	1	1	0	0	0	0
-1	1	0	0	0	0	0	0	1		-49	1	0	1	1	0	0	0	1
-2	1	0	0	0	0	0	1	0		-50	1	0	1	1	0	0	1	0
-3	1	0	0	0	0	0	1	1		-51	1	0	1	1	0	0	1	1
-4	1	0	0	0	0	1	0	0		-52	1	0	1	1	0	1	0	0
-5	1	0	0	0	0	1	0	1		-53	1	0	1	1	0	1	0	1
-6	1	0	0	0	0	1	1	0		-54	1	0	1	1	0	1	1	0
-7	1	0	0	0	0	1	1	1		-55	1	0	1	1	0	1	1	1
-8	1	0	0	0	1	0	0	0		-56	1	0	1	1	1	0	0	0
-9	1	0	0	0	1	0	0	1		-57	1	0	1	1	1	0	0	1
-10	1	0	0	0	1	0	1	0		-58	1	0	1	1	1	0	1	0
-11	1	0	0	0	1	0	1	1		-59	1	0	1	1	1	0	1	1
-12	1	0	0	0	1	1	0	0		-60	1	0	1	1	1	1	0	0
-13	1	0	0	0	1	1	0	1		-61	1	0	1	1	1	1	0	1
-14	1	0	0	0	1	1	1	0		-62	1	0	1	1	1	1	1	0
-15	1	0	0	0	1	1	1	1		-63	1	0	1	1	1	1	1	1
-16	1	0	0	1	0	0	0	0		-64	1	1	0	0	0	0	0	0
-17 -18	1	0	0	1	0	0	0	1 0		-65 -66	1	1	0	0	0	0 0	0	1
			0	1		-		1							0			0
-19 -20	1	0	0	1	0 0	0	1	0		-67 -68	1	1	0	0	0	0	1 0	1 0
-20 -21	1	0	0	1	0	1	0	1		-68 -69	1	1	0	0	0	1	0	1
-21	1	0	0	1	0	1	1	0		-69 -70	1	1	0	0	0	1	1	0
-22	1	0	0	1	0	1	1	1		-70	1	1	0	0	0	1	1	1
-23	1	0	0	4	1	0	0	0		-71	4	1	0	0	1	0	0	0
-24 -25	1	0	0	1	1	0	0	1		-72	1	1	0	0	1	0	0	1
-25	1	0	0	1	1	0	1	0		-73	1	1	0	0	1	0	1	0
-20	1	0	0	1	1	0	1	1		-74	1	1	0	0	1	0	1	1
-27	1	0	0	1	1	1	0	0		-75	1	1	0	0	1	1	0	0
-20	1	0	0	1	1	1	0	1		-78	1	1	0	0	1	1	0	1
-29	1	0	0	1	1	1	1	0		-77	1	1	0	0	1	1	1	0
-30	1	0	0	1	1	1	1	1		-78	1	1	0	0	1	1	1	1
-31	1	0	1	0	0	0	0	0		-73	1	1	1	1	1	1	1	1
-02		U	. – –			0	0	U										

Mixing Adjustable range is +7dB to -∞dB.

: Initial condition

## 3. Application Circuit



## Notes on wiring

- ① Please connect the decoupling capacitor of the power supply in the shortest possible distance to GND.
- ② GND lines should be one-point connected.
- ③ Wiring pattern of Digital shall be away from that of analog unit and crosstalk should not be acceptable.
- ④ If possible, SCL and SDA lines of I<sup>2</sup>C BUS should not be in parallel. The lines should be shielded, if they are adjacent to each other.
- 5 If possible, analog input lines should not be in parallel. The lines should be shielded, if they are adjacent to each other.
- 6 TEST pins (Pin 16, 17) should be OPEN.

## **Power Dissipation**

About the thermal design of the IC

Characteristics of an IC are greatly affected by the temperature at which it is used exceeding absolute maximum ratings may degrade and destroy the device. Careful consideration must be given to the heat of the IC from the two standpoints of immediate damage and long-term reliability of operation.

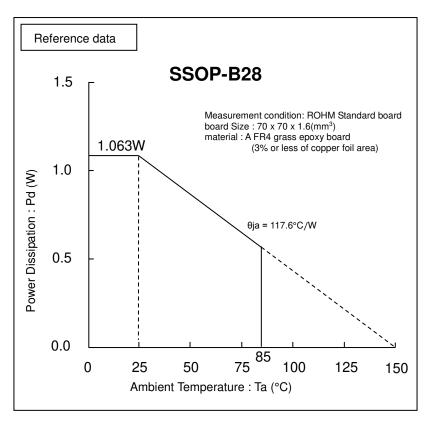


Figure 23. Temperature Derating Curve

(Note) Values are actual measurements and are not guaranteed.

Power dissipation values vary according to the board on which the IC is mounted.

## I/O Equivalent Circuits

Terminal No.	Terminal Name	Terminal Voltage	Equivalent Circuit	Terminal Description
1 2 3 4 5 6	A1 A2 B1 B2 C1 C2	4.25	VCC VCC V V V V V V V V V V V V V V V V	A terminal for signal input. The input impedance is 100kΩ (typ).
7 8 9 10 11 12 13	DP1 DN DP2 EP1 EN1 EN2 EP2	4.25		Input terminal available to Single/Differential mode. The input impedance is 250kΩ (typ).
15	MUTE	-	VCC	A terminal for external compulsory mute. If terminal voltage is High level, the mute is off. And if the terminal voltage is Low level, the mute is ON.
18 19 20 21 22 23	OUTS2 OUTS1 OUTR2 OUTR1 OUTF2 OUTF1	4.25	VCC M M M M M M M M M M M M M M M M M M	A terminal for Fader and Subwoofer output.

Values in the pin explanation and input/output equivalent circuit are for reference purposes only. It is not a guaranteed value.

#### I/O Equivalent Circuits - continued

D Equivalen	t Circuits	- continue	d	
Terminal No.	Terminal Name	Terminal Voltage	Equivalent Circuit	Terminal Description
24	VCC	8.5		Power supply terminal.
25	SCL	-	VCC	A terminal for clock input of I <sup>2</sup> C BUS communication.
26	SDA	-	VCC	A terminal for data input of I <sup>2</sup> C BUS communication.
27	GND	0		Ground terminal.
28	FIL	4.25		Voltage for reference bias of analog signal system. The simple precharge circuit and simple discharge circuit for an external capacitor are built in.
14	MIN	4.25		A terminal for signal input The input impedance is 27kΩ (typ).
16 17	TEST	-		TEST terminal

Values in the pin explanation and input/output equivalent circuit are for reference purposes only. It is not a guaranteed value.

## **Operational Notes**

## 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

## 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

## 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

## 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

## 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

## 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

## 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

## 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

## 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

## 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

## **Operational Notes – continued**

## 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

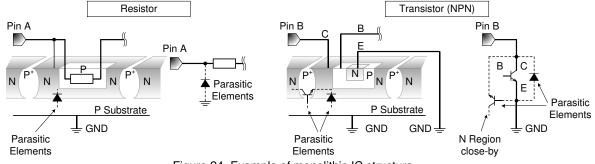
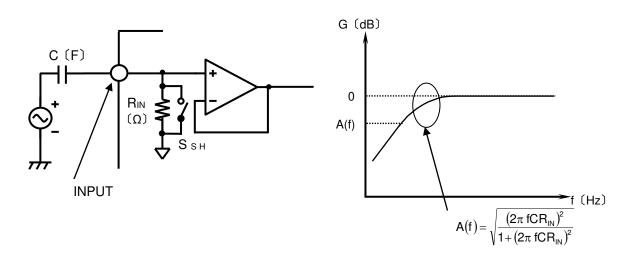


Figure 24. Example of monolithic IC structure

## 13. About a Signal Input Part

(a) About Input Coupling Capacitor Constant Value

The constant value of input coupling capacitor C(F) is decided with respect to the input impedance  $R_{IN}(\Omega)$  at the input signal terminal of the IC that would be sufficient to form an RC characterized HPF.



(b) About the Input Selector SHORT

SHORT mode is the command which makes switch  $S_{SH} = ON$  of input selector part so that the input impedance  $R_{IN}$  of all terminals becomes small. Switch  $S_{SH}$  is OFF when SHORT command is not selected. The constant time brought about by the small resistance inside and the capacitor outside the LSI becomes small when this command is used. The charge time of the capacitor becomes short. Since SHORT mode turns ON the switch of  $S_{SH}$  and makes it low impedance, please use it at no signal condition.

## 14. About Mute Terminal (Pin 15) when Power Supply is OFF

There should be no applied voltage to Mute terminal (Pin 15) when power-supply is OFF. If in case voltage is supplied to MUTE terminal, please insert a series resistor (about  $2.2k\Omega$ ) to Mute terminal. (Please refer to Application Circuit Diagram.)

## 15. About TEST Pin

TEST Pin should be OPEN. Pin 16,17 are TEST Pins.

## **Operational Notes – continued**

## 16. About Mixing

(a) <u>About Specification of Fader -∞ at Mixing ON.</u>

Mixed signal is added to the Main signal together with the Fader Gain (+15dB to -79dB) shown in the figure below. When Fader is set up in  $-\infty$ , the signal after MIX is added with MUTE because the  $-\infty$  circuit of Fader is in the step after the addition circuit.

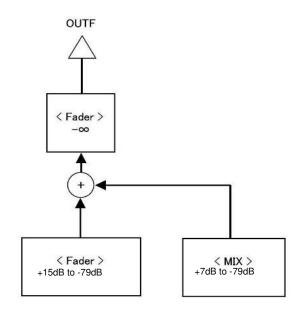
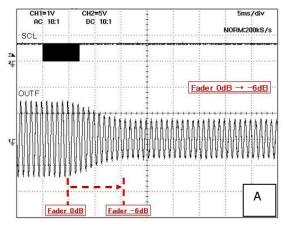


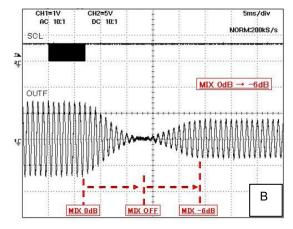
Figure 25. About Front Fader and Mixing

(b) About Advanced switching of Mixing Gain/ATT

When advanced switching of Mixing Gain/ATT works, Mixing becomes a switching movement that it passes through the state of Mixing OFF like what is shown in Figure B (from present setup of Mixing Gain/ATT to Mixing OFF to a target setup of Mixing Gain/ATT).



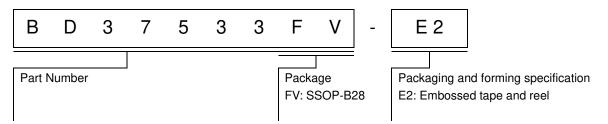
Fader Gain/ATT 0dB to -6dB Advanced Switching



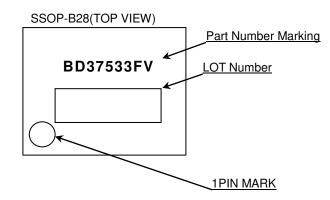
Mixing Gain/ATT 0dB to -6dB Advanced Switching

Figure 26. Advanced Switching Movement when Mixing Gain/ATT is changed

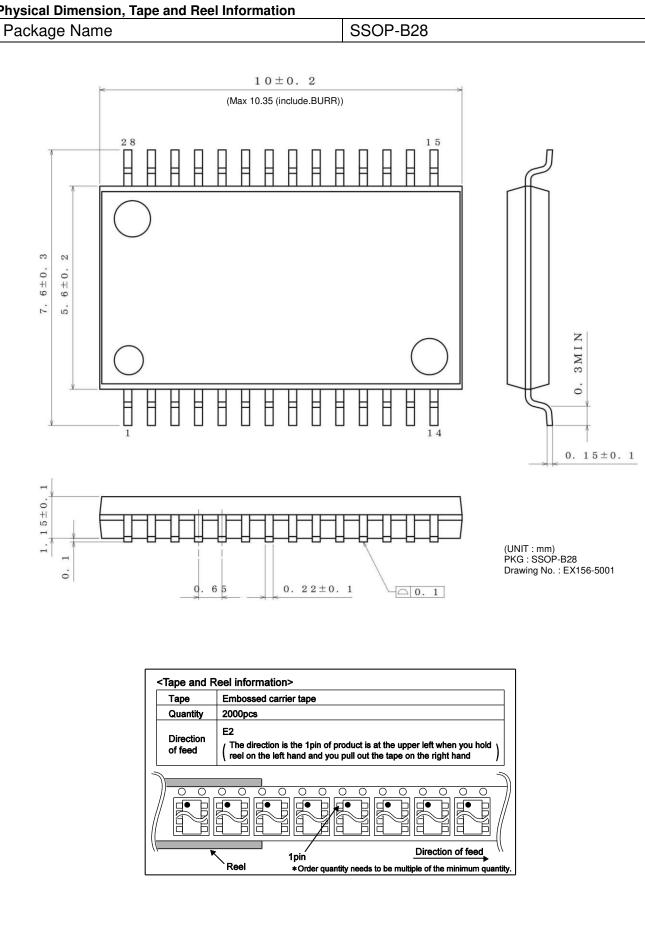
## **Ordering Information**



## **Marking Diagram**



## Physical Dimension, Tape and Reel Information



## **Revision History**

Date	Revision	Changes
16.Dec.2015	001	New Release

# Notice

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(Note1) Medical Equipment Classification of the Specific Applications
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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ	CLASSII	CLASSⅢ	CLASSII

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  - [d] the Products are exposed to high Electrostatic
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